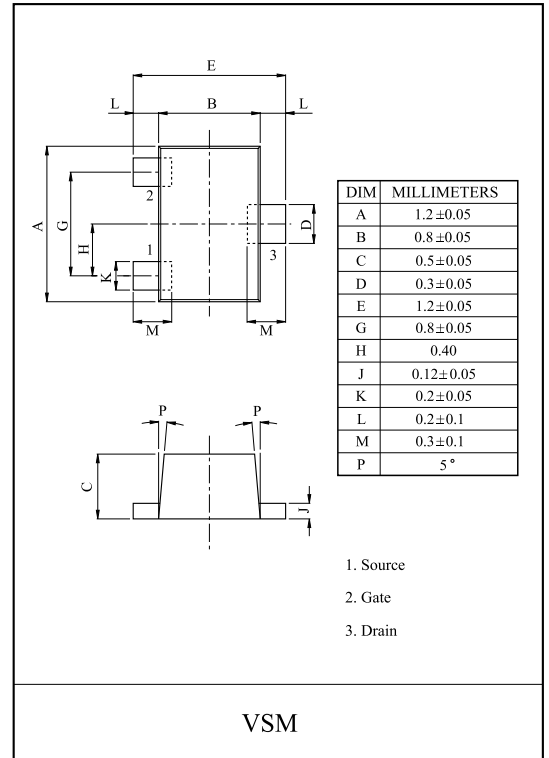


General Description

It is mainly suitable for Load Switching Cell Phones, Battery Powered Systems and Level-Shifter.

FEATURES

- $V_{DSS}=20V$, $I_D=0.4A$
- Drain-Source ON Resistance
 - : $R_{DS(ON)}=0.70$ @ $V_{GS}=4.5V$
 - : $R_{DS(ON)}=0.85$ @ $V_{GS}=2.5V$
 - : $R_{DS(ON)}=1.25$ @ $V_{GS}=1.8V$
- Super High Dense Cell Design

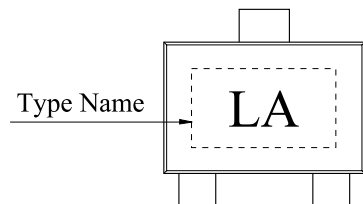


MAXIMUM RATING (Ta=25 °C)

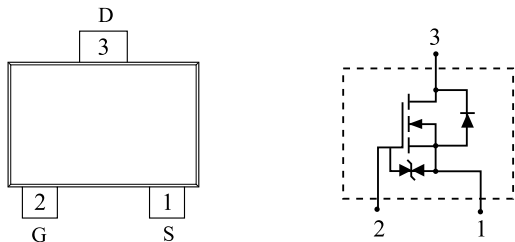
CHARACTERISTIC		SYMBOL	N-Ch	UNIT
Drain-Source Voltage		V_{DSS}	20	V
Gate-Source Voltage		V_{GSS}	± 6	V
Drain Current	DC @ $T_A=25$	I_D^*	400	mA
	DC @ $T_A=85$		280	
	Pulsed	I_{DP}	650	
Source-Drain Diode Current		I_S	125	
Drain Power Dissipation		P_D^*	150	mW
Maximum Junction Temperature		T_j	150	
Storage Temperature Range		T_{stg}	-55 150	

Note 1) *Surface Mounted on 1 × 1 FR4 Board. t = 5 sec

Marking



PIN CONNECTION (TOP VIEW)



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ELECTRICAL CHARACTERISTICS (Ta=25)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=250\ \mu A, V_{GS}=0V$	20	-	-	V
Drain Cut-off Current	I_{DSS}	$V_{GS}=0V, V_{DS}=16V$	-	0.3	100	nA
Gate Leakage Current	I_{GSS}	$V_{GS}=\pm 4.5V, V_{DS}=0V$	-	± 0.5	± 1.0	μA
Gate Threshold Voltage	V_{th}	$V_{DS}=V_{GS}, I_D=250\ \mu A$	0.45	-	1.0	V
Drain-Source ON Resistance	$R_{DS(ON)}^*$	$V_{GS}=4.5V, I_D=400mA$	-	0.41	0.70	
		$V_{GS}=2.5V, I_D=350mA$	-	0.53	0.85	
		$V_{GS}=1.8V, I_D=300mA$	-	0.70	1.25	
Forward Transconductance	g_{fs}^*	$V_{DS}=10V, I_D=400mA$	-	1.0	-	S
Source-Drain Diode Forward Voltage	V_{SD}^*	$I_S=150mA, V_{GS}=0V$	-	0.8	1.2	V
Dynamic						
Total Gate Charge	Q_g^*	$V_{DS}=10V, I_D=250mA, V_{GS}=4.5V$	-	750	-	pC
Gate-Source Charge	Q_{gs}^*		-	75	-	
Gate-Drain Charge	Q_{gd}^*		-	225	-	
Turn-on Delay time	$t_{d(on)}^*$	$V_{DD}=10V, I_D=200mA, V_{GS}=4.5V, R_G=10$	-	5	-	ns
Turn-off Delay time	$t_{d(off)}^*$		-	25	-	

Note 2) *Pulse test : Pulse width 300 μs , Duty Cycle 2%.

Fig 1. $I_D - V_{DS}$

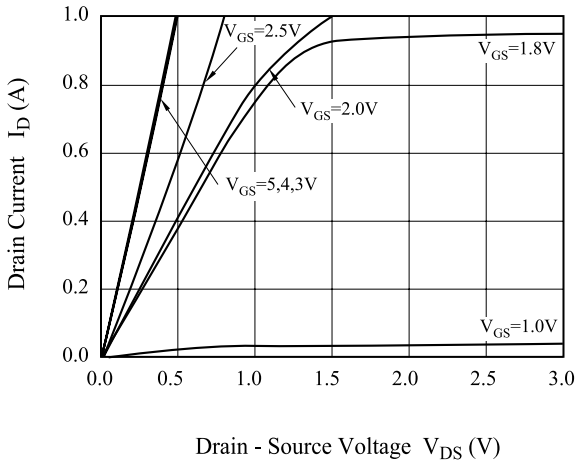


Fig 2. $R_{DS(on)} - I_D$

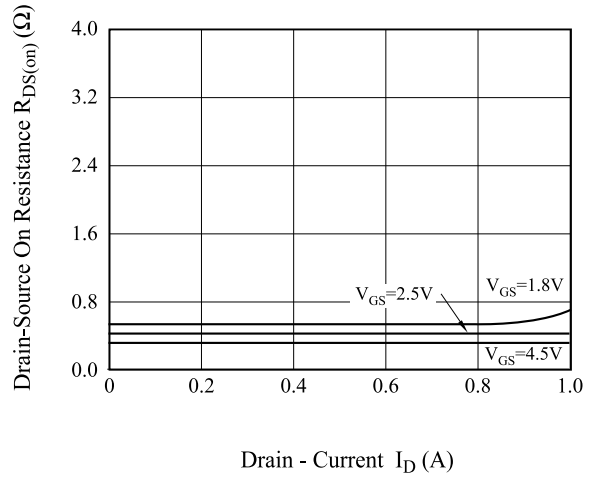


Fig 3. $I_D - V_{GS}$

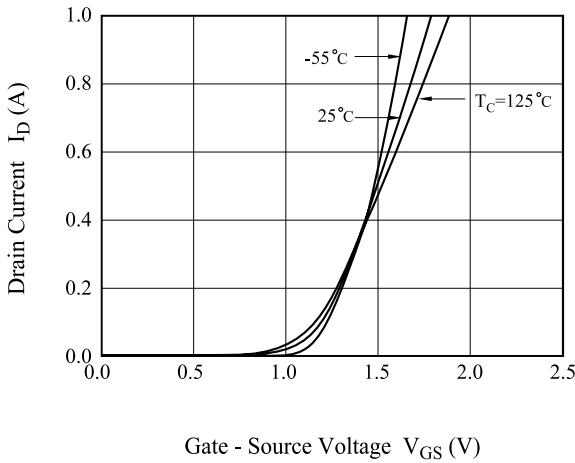


Fig 4. $R_{DS(ON)} - T_j$

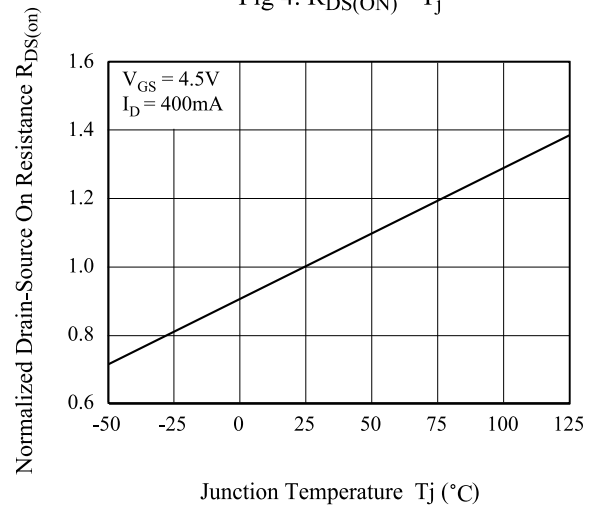


Fig 5. $V_{th} - T_j$

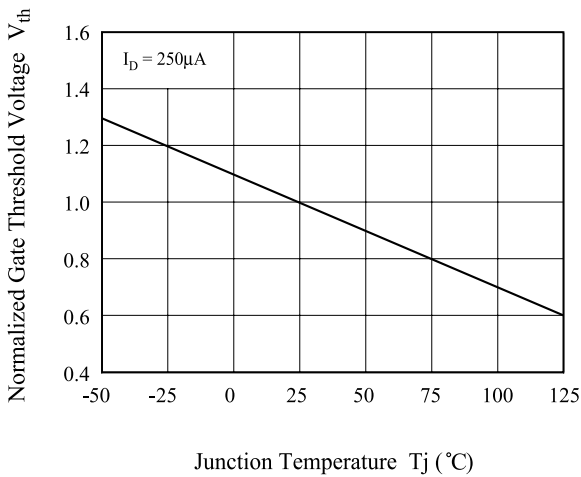
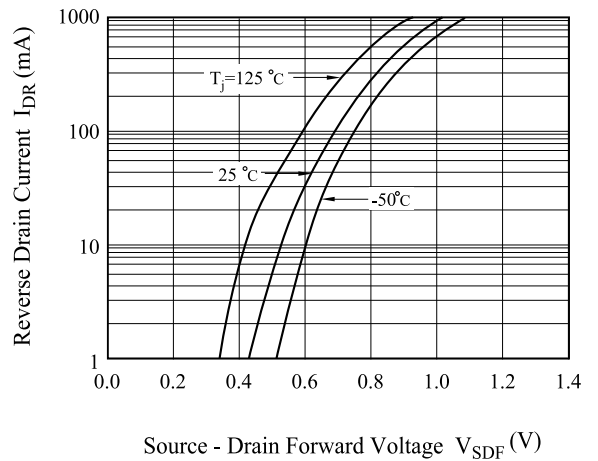


Fig 6. $I_{DR} - V_{SDF}$



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Fig 7. $V_{GS} - Q_g$

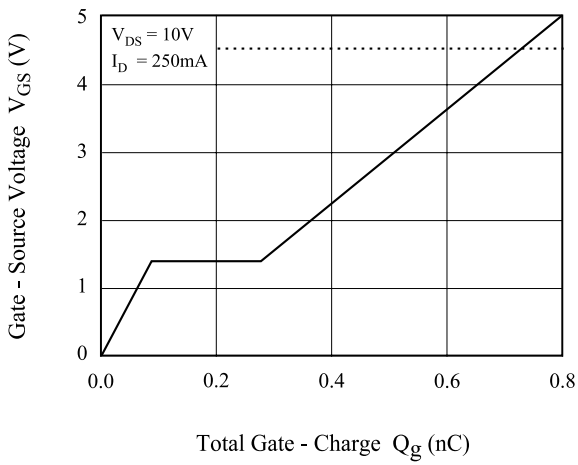


Fig 8. $C - V_{DS}$

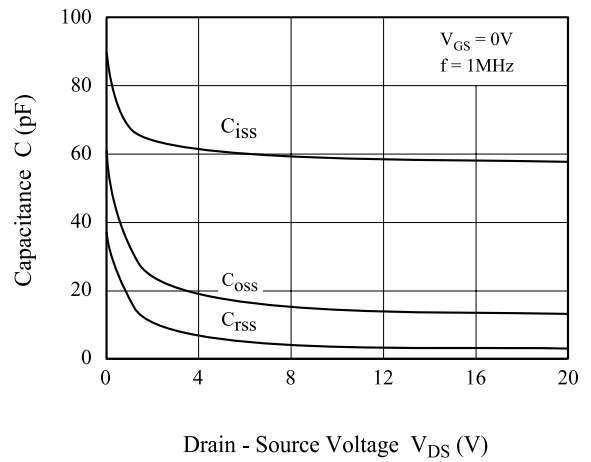


Fig 9. Transient Thermal Response Curve

